

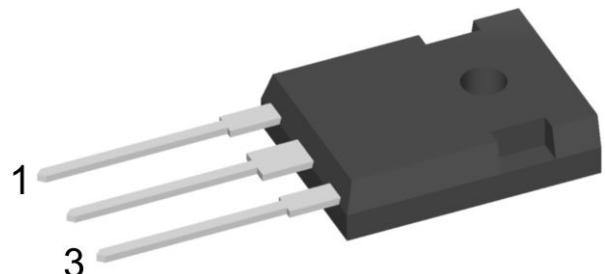
## Schottky Diode Gen 2

$V_{RRM}$  = 200V  
 $I_{FAV}$  = 2x 45A  
 $V_F$  = 0.79V

High Performance Schottky Diode  
Low Loss and Soft Recovery  
Common Cathode

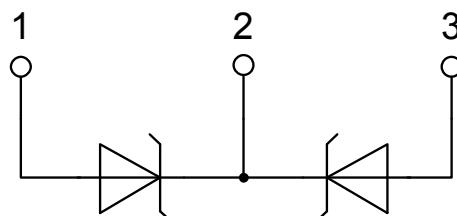
Part number

DSA90C200HR



Backside: isolated

E72873



### Features / Advantages:

- Very low  $V_F$
- Extremely low switching losses
- Low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

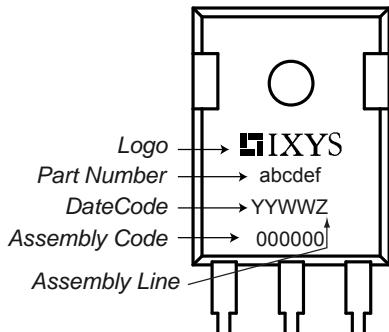
### Package: ISO247

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

**Schottky**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			200	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			200	V
$I_R$	reverse current, drain current	$V_R = 200 V$ $V_R = 200 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		2 5	mA
$V_F$	forward voltage drop	$I_F = 45 A$ $I_F = 90 A$ $I_F = 45 A$ $I_F = 90 A$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		0.91 1.10 0.79 1.03	V
$I_{FAV}$	average forward current	$T_C = 145^\circ C$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ C$		45	A
$V_{F0}$ $r_F$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175^\circ C$		0.49 5.5	V mΩ
$R_{thJC}$	thermal resistance junction to case				0.7	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.25		K/W
$P_{tot}$	total power dissipation	$T_C = 25^\circ C$			215	W
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 V$	$T_{VJ} = 45^\circ C$		600	A
$C_J$	junction capacitance	$V_R = 24 V$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$	394		pF

Package ISO247			Ratings		
Symbol	Definition	Conditions	min.	typ.	max.
$I_{RMS}$	$RMS$ current	per terminal <sup>1)</sup>			70 A
$T_{VJ}$	virtual junction temperature		-55		175 °C
$T_{op}$	operation temperature		-55		150 °C
$T_{stg}$	storage temperature		-55		150 °C
<b>Weight</b>				6	g
$M_D$	mounting torque		0.8		1.2 Nm
$F_c$	mounting force with clip		20		120 N
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	2.7		mm
$d_{Spb/Abp}$		terminal to backside	4.1		mm
$V_{ISOL}$	isolation voltage	$t = 1$ second $t = 1$ minute	3600 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3000	V V

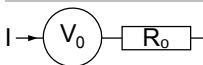
**Product Marking****Part number**

D = Diode  
 S = Schottky Diode  
 A = low VF  
 90 = Current Rating [A]  
 C = Common Cathode  
 200 = Reverse Voltage [V]  
 HR = ISO247 (3)

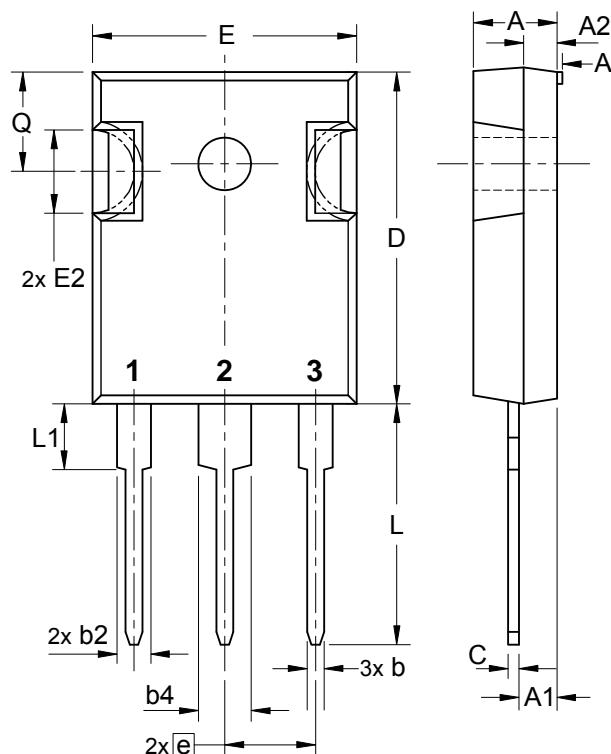
Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA90C200HR	DSA90C200HR	Tube	30	508368

Similar Part	Package	Voltage class
DSSK60-02AR	ISOPLUS247 (3)	200
DSSK60-02A	TO-247AD (3)	200

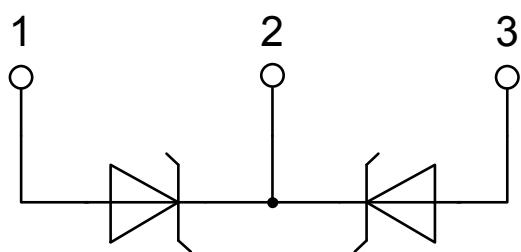
**Equivalent Circuits for Simulation**<sup>\*</sup> on die level $T_{VJ} = 175$  °C

	Schottky
$V_{0\max}$	threshold voltage
$R_{0\max}$	slope resistance *

## Outlines ISO247



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.70	5.30	0.185	0.209
A1	2.21	2.59	0.087	0.102
A2	1.50	2.49	0.059	0.098
A3	typ. 0.05		typ. 0.002	
b	0.99	1.40	0.039	0.055
b2	1.65	2.39	0.065	0.094
b4	2.59	3.43	0.102	0.135
c	0.38	0.89	0.015	0.035
D	20.79	21.45	0.819	0.844
D1	typ. 8.90		typ. 0.350	
D2	typ. 2.90		typ. 0.114	
D3	typ. 1.00		typ. 0.039	
E	15.49	16.24	0.610	0.639
E1	typ. 13.45		typ. 0.530	
E2	4.31	5.48	0.170	0.216
E3	typ. 4.00		typ. 0.157	
e	5.46	BSC	0.215	BSC
L	19.80	20.30	0.780	0.799
L1	-	4.49	-	0.177
Ø P	3.55	3.65	0.140	0.144
Q	5.38	6.19	0.212	0.244
S	6.14	BSC	0.242	BSC



## Schottky

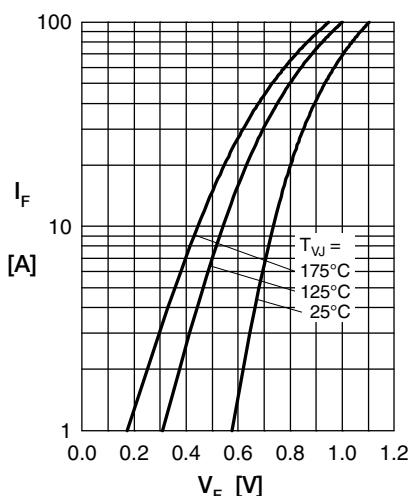


Fig. 1 Max. forward voltage drop characteristics

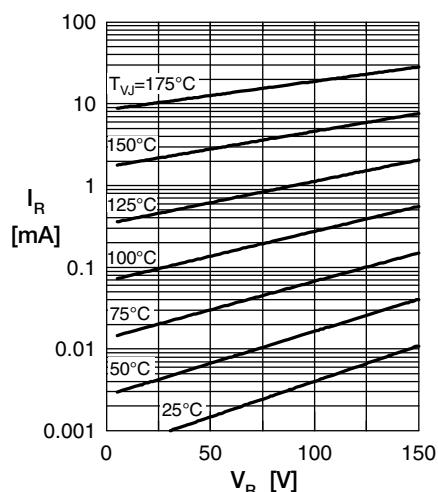
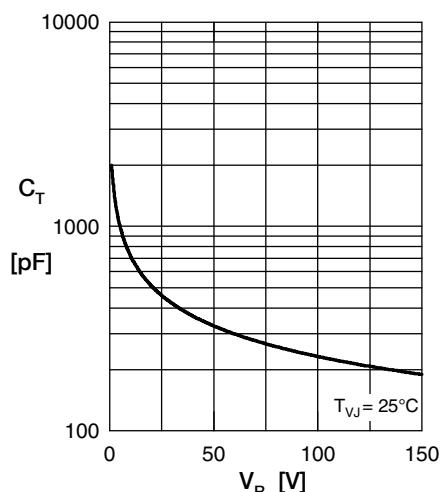
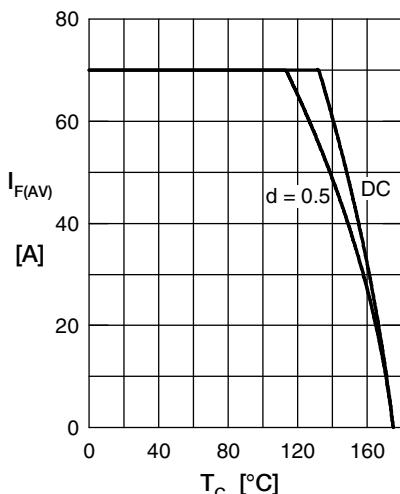
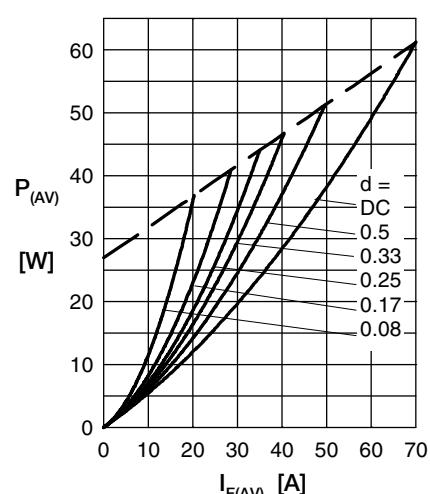
Fig. 2 Typ. reverse current  $I_R$  vs. reverse voltage  $V_R$ Fig. 3 Typ. junction capacitance  $C_T$  vs. reverse voltage  $V_R$ Fig. 4 Avg. forward current  $I_{F(AV)}$  vs. case temp.  $T_C$ 

Fig. 5 Forward power loss characteristics

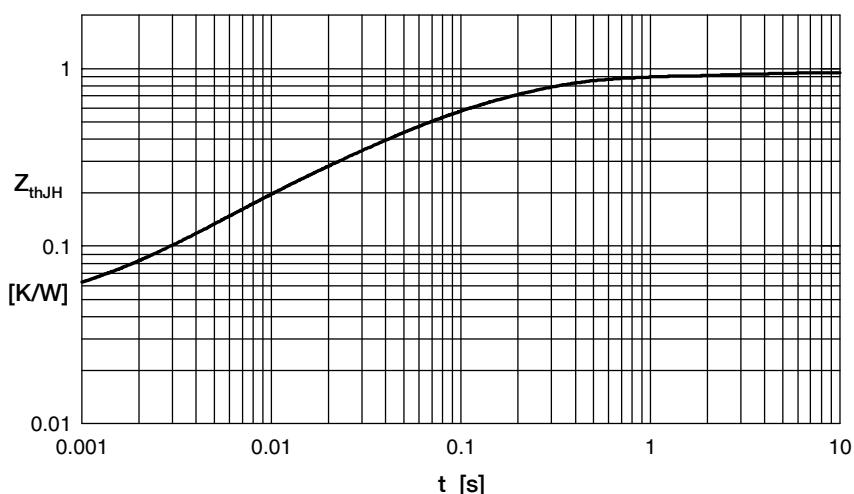


Fig. 6 Transient thermal impedance junction to heatsink

$R_{thi}$	$t_i$
0.041	0.0002
0.087	0.0065
0.258	0.037
0.486	0.182
0.078	2.43

Note: All curves are per diode